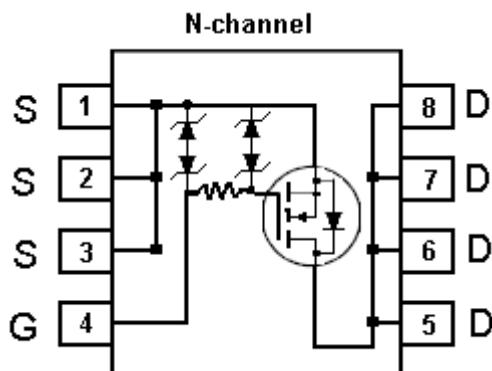




# TSM7401

## 20V N-Channel MOSFET w/ESD Protected

<b>SOP-8</b> 	Pin assignment: 1. Source 2. Source 3. Source 4. Gate 5, 6, 7, 8. Drain	$V_{DS} = 20V$ $R_{DS(on)}, V_{GS} @ 4.5V, I_{DS} @ 4.5A = 20m\Omega$ $R_{DS(on)}, V_{GS} @ 2.7V, I_{DS} @ 3.5A = 25m\Omega$
<b>Features</b> <ul style="list-style-type: none"><li>◊ Advanced trench process technology</li><li>◊ High density cell design for ultra low on-resistance</li><li>◊ Excellent thermal and electrical capabilities</li><li>◊ Specially designed for Li-ion battery packs.</li><li>◊ Battery switch application</li></ul>		<b>Block Diagram</b> 
<b>Ordering Information</b>		

### Absolute Maximum Rating ( $T_a = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	$V_{DS}$	20V	V	
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V	
Continuous Drain Current, $V_{GS} @ 4.5V$ .	$I_D$	8	A	
Pulsed Drain Current, $V_{GS} @ 4.5V$	$I_{DM}$	30	A	
Maximum Power Dissipation	$T_a = 25^\circ C$	$P_D$	W	
		2.5		
Operating Junction Temperature		$T_J$	$+150$	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55 to +150	

### Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Foot (Drain) Thermal Resistance	$R_{\theta Jf}$	30	$^\circ C/W$
Junction to Ambient Thermal Resistance (PCB mounted)	$R_{\theta ja}$	50	$^\circ C/W$

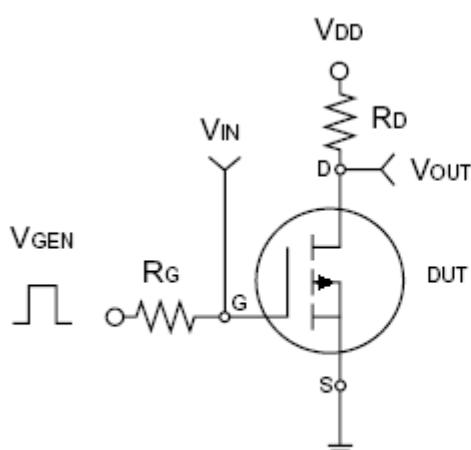
Note: Surface mounted on FR4 board  $t \leq 10\text{ sec}$ .

## Electrical Characteristics

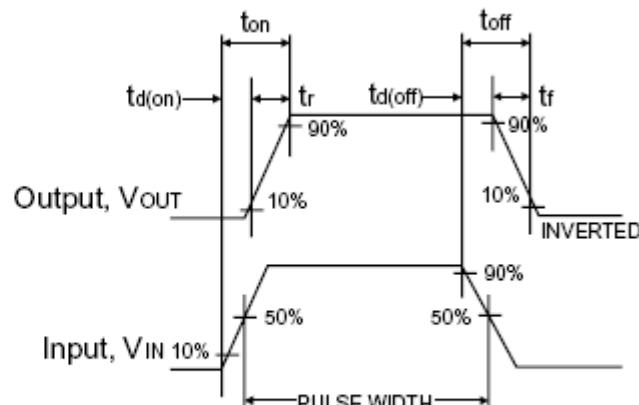
(Ta = 25 °C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250uA	BV <sub>DSS</sub>	20	--	--	V
Drain-Source On-State Resistance	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 4.5A	R <sub>DS(ON)</sub>	--	20	25	mΩ
Drain-Source On-State Resistance	V <sub>GS</sub> = 2.7V, I <sub>D</sub> = 3.5A	R <sub>DS(ON)</sub>	--	25	30	
Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250uA	V <sub>GS(TH)</sub>	0.65	0.85	--	V
Zero Gate Voltage Drain Current	V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0V	I <sub>DSS</sub>	--	--	1.0	uA
Gate Body Leakage	V <sub>GS</sub> = ± 4.5V, V <sub>DS</sub> = 0V	I <sub>GSS</sub>	--	--	± 100	nA
On-State Drain Current	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> >= 5V	I <sub>D(ON)</sub>	30	--	--	A
Forward Transconductance	V <sub>DS</sub> = 10V, I <sub>D</sub> = 4.5A	g <sub>fs</sub>	--	30	--	S
<b>Dynamic</b>						
Total Gate Charge	V <sub>DS</sub> = 10V, I <sub>D</sub> = 4.5A, V <sub>GS</sub> = 4.5V	Q <sub>g</sub>	--	15.5	35	nC
Gate-Source Charge		Q <sub>gs</sub>	--	3	--	
Gate-Drain Charge		Q <sub>gd</sub>	--	5	--	
Turn-On Delay Time	V <sub>DD</sub> = 10V, R <sub>L</sub> = 10Ω, I <sub>D</sub> = 1A, V <sub>GEN</sub> = 4.5V, R <sub>G</sub> = 6Ω	t <sub>d(on)</sub>	--	75	100	nS
Turn-On Rise Time		t <sub>r</sub>	--	125	150	
Turn-Off Delay Time		t <sub>d(off)</sub>	--	600	720	
Turn-Off Fall Time		t <sub>f</sub>	--	300	360	
Input Capacitance	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V, f = 1.0MHz	C <sub>iss</sub>	--	1336	--	pF
Output Capacitance		C <sub>oss</sub>	--	220	--	
Reverse Transfer Capacitance		C <sub>rss</sub>	--	130	--	
<b>Source-Drain Diode</b>						
Max. Diode Forward Current		I <sub>S</sub>	--	--	2.0	A
Diode Forward Voltage	I <sub>S</sub> = 2.0A, V <sub>GS</sub> = 0V	V <sub>SD</sub>	--	0.6	1.2	V

Note : pulse test: pulse width <=300uS, duty cycle <=2%

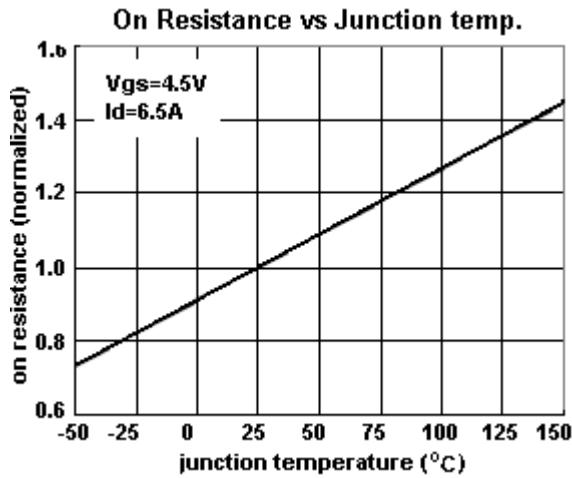
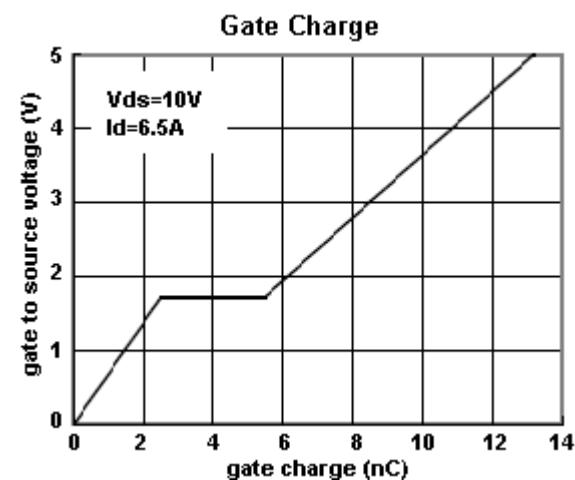
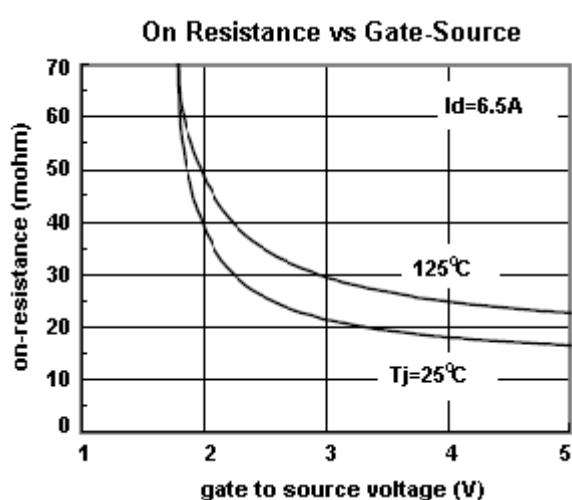
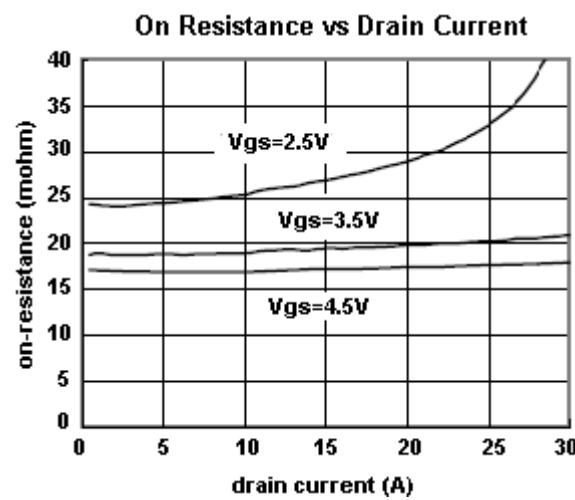
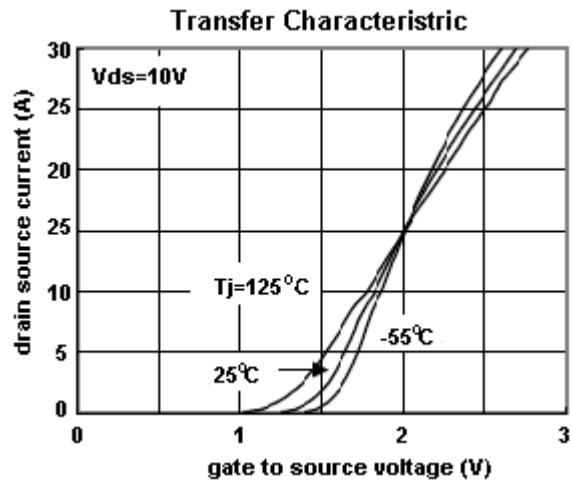
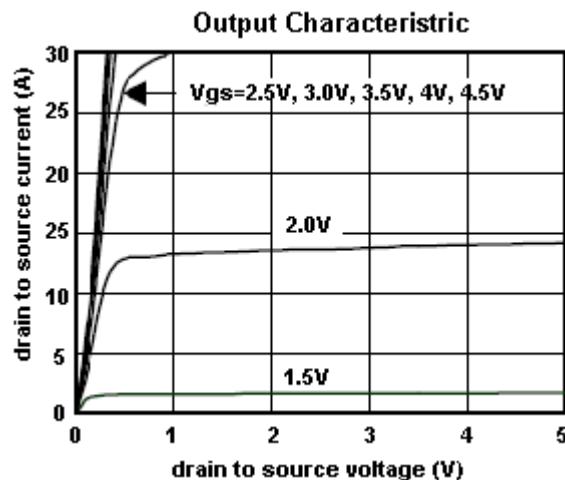


Switching Test Circuit

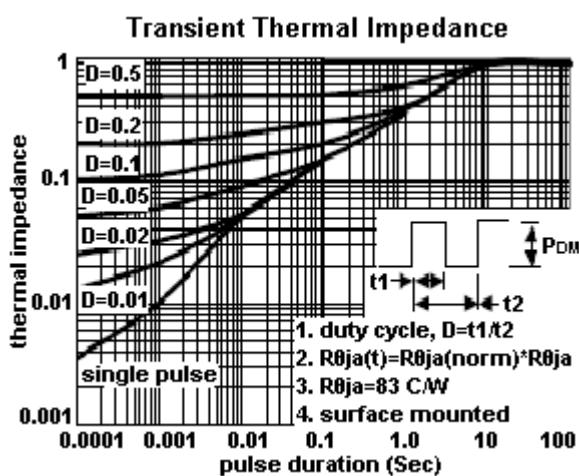
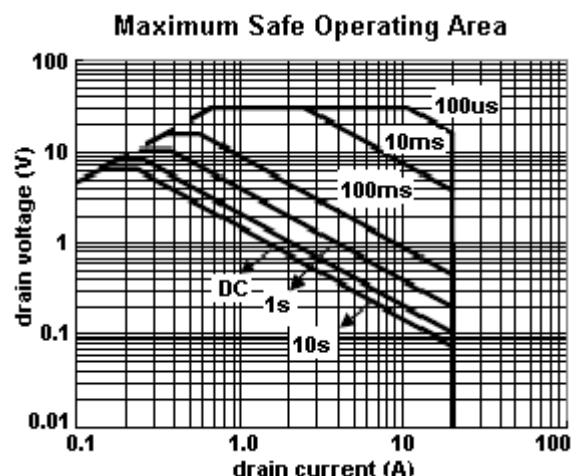
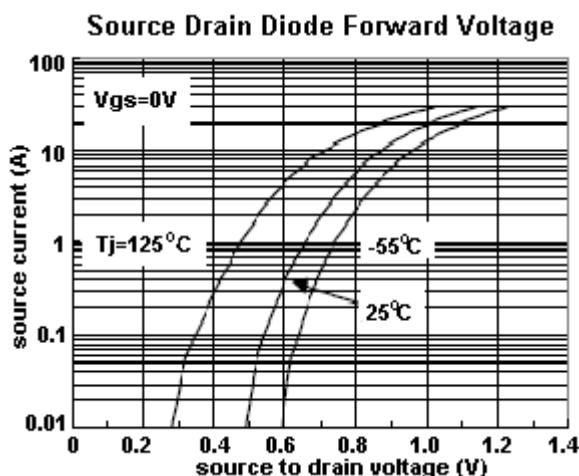
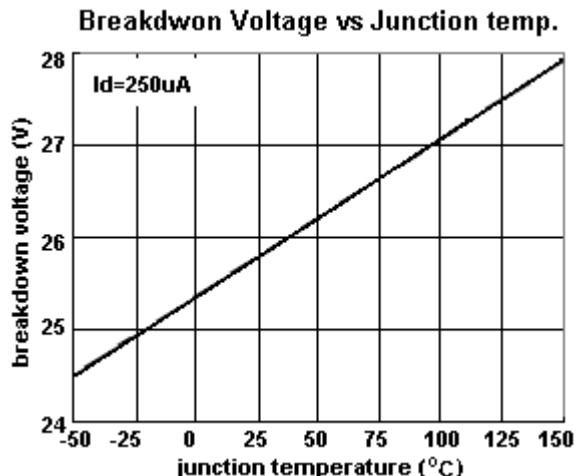
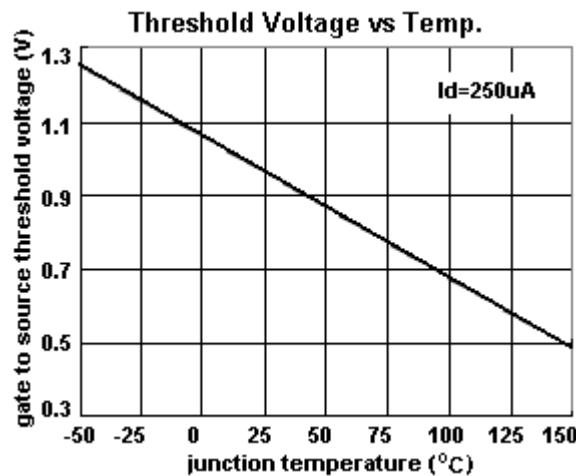


Switchin Waveforms

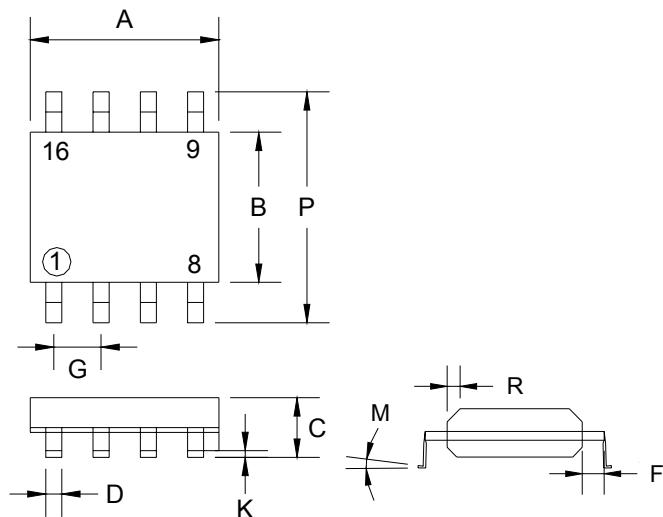
**Typical Characteristics Curve** ( $T_a = 25^\circ\text{C}$  unless otherwise noted)



## Electrical Characteristics Curve (continued)



## SOP-8 Mechanical Drawing



SOP-8 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.196
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 (typ)		0.05 (typ)	
K	0.10	0.25	0.004	0.009
M	$0^\circ$	$7^\circ$	$0^\circ$	$7^\circ$
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019